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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

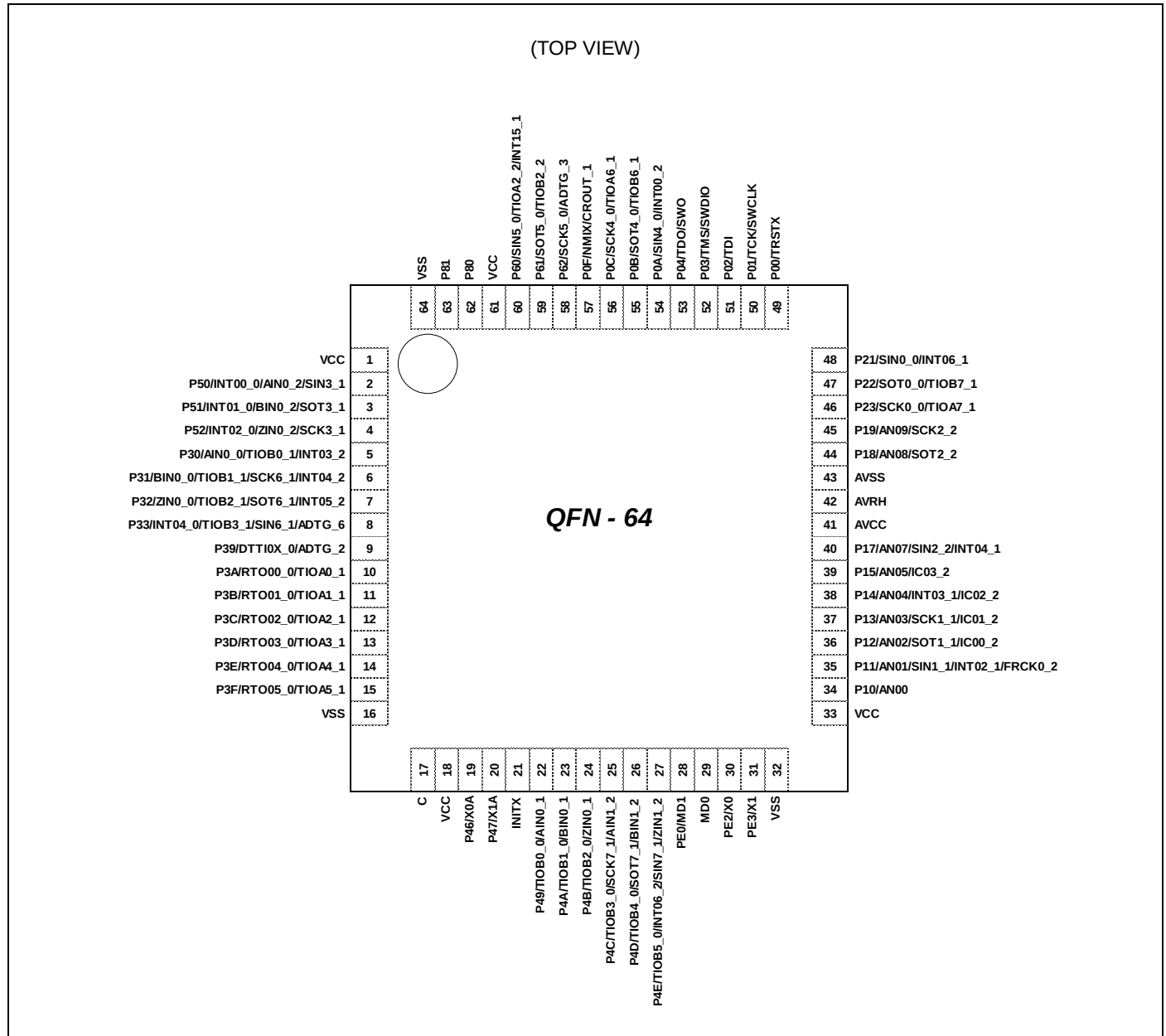
Details

Product Status	Obsolete
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	40MHz
Connectivity	CSIO, EBI/EMI, I ² C, LINbus, SPI, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	66
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy9af116mapmc-g-mne2

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VNC064



Note:

The number after the underscore ("_") in pin names such as XXX_1 and XXX_2 indicates the relocated port number. For these pins, there are multiple pins that provide the same function for the same channel. Use the extended port function register (EPFR) to select the pin.

4. List of Pin Functions

List of pin numbers

The number after the underscore ("_") in pin names such as XXX_1 and XXX_2 indicates the relocated port number. For these pins, there are multiple pins that provide the same function for the same channel. Use the extended port function register (EPFR) to select the pin.

Pin No					Pin name	I/O circuit type	Pin state type
LQFP-100	QFP-100	BGA-112	LQFP-80	LQFP-64 QFN-64			
1	79	B1	1	1	VCC	-	
2	80	C1	2	2	P50	E	H
					INT00_0		
					AIN0_2		
					SIN3_1		
			-	-	RTO10_0 (PPG10_0)		
					MADATA00_1		
3	81	C2	3	3	P51	E	H
					INT01_0		
					BIN0_2		
					SOT3_1 (SDA3_1)		
			-	-	RTO11_0 (PPG10_0)		
					MADATA01_1		
4	82	B3	4	4	P52	E	H
					INT02_0		
					ZIN0_2		
					SCK3_1 (SCL3_1)		
			-	-	RTO12_0 (PPG12_0)		
					MADATA02_1		
5	83	D1	5	-	P53	E	H
					SIN6_0		
					TIOA1_2		
					INT07_2		
					RTO13_0 (PPG12_0)		
					MADATA03_1		
6	84	D2	6	-	P54	E	I
					SOT6_0 (SDA6_0)		
					TIOB1_2		
					RTO14_0 (PPG14_0)		
					MADATA04_1		

Module	Pin name	Function	Pin No				
			LQFP-100	QFP-100	BGA-112	LQFP-80	LQFP-64 QFN-64
Multi Function Serial 0	SIN0_0	Multifunction serial interface ch.0 input pin	73	51	C11	59	48
	SIN0_1		56	34	H9	46	-
	SOT0_0 (SDA0_0)	Multifunction serial interface ch.0 output pin. This pin operates as SOT0 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA0 when it is used in an I ² C (operation mode 4).	72	50	E8	58	47
	SOT0_1 (SDA0_1)		57	35	H7	47	-
	SCK0_0 (SCL0_0)	Multifunction serial interface ch.0 clock I/O pin. This pin operates as SCK0 when it is used in a CSIO (operation mode 2) and as SCL0 when it is used in an I ² C (operation mode 4).	71	49	D10	57	46
	SCK0_1 (SCL0_1)		58	36	G10	48	-
Multi Function Serial 1	SIN1_1	Multifunction serial interface ch.1 input pin	53	31	J10	43	35
	SOT1_1 (SDA1_1)	Multifunction serial interface ch.1 output pin. This pin operates as SOT1 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA1 when it is used in an I ² C (operation mode 4).	54	32	J8	44	36
	SCK1_1 (SCL1_1)	Multifunction serial interface ch.1 clock I/O pin. This pin operates as SCK1 when it is used in a CSIO (operation mode 2) and as SCL1 when it is used in an I ² C (operation mode 4).	55	33	H10	45	37
Multi Function Serial 2	SIN2_2	Multifunction serial interface ch.2 input pin	59	37	G9	49	40
	SOT2_2 (SDA2_2)	Multifunction serial interface ch.2 output pin. This pin operates as SOT2 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA2 when it is used in an I ² C (operation mode 4).	63	41	G8	53	44
	SCK2_2 (SCL2_2)	Multifunction serial interface ch.2 clock I/O pin. This pin operates as SCK2 when it is used in a CSIO (operation mode 2) and as SCL2 when it is used in an I ² C (operation mode 4).	64	42	F10	54	45
Multi Function Serial 3	SIN3_1	Multifunction serial interface ch.3 input pin	2	80	C1	2	2
	SIN3_2		39	17	K6	29	-
	SOT3_1 (SDA3_1)	Multifunction serial interface ch.3 output pin. This pin operates as SOT3 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA3 when it is used in an I ² C (operation mode 4).	3	81	C2	3	3
	SOT3_2 (SDA3_2)		40	18	J6	30	-
	SCK3_1 (SCL3_1)	Multifunction serial interface ch.3 clock I/O pin. This pin operates as SCK3 when it is used in a CSIO (operation mode 2) and as SCL3 when it is used in an I ² C (operation mode 4).	4	82	B3	4	4
	SCK3_2 (SCL3_2)		41	19	L7	31	-

Module	Pin name	Function	Pin No				
			LQFP-100	QFP-100	BGA-112	LQFP-80	LQFP-64 QFN-64
Multi Function Serial 6	SIN6_0	Multifunction serial interface ch.6 input pin	5	83	D1	5	-
	SIN6_1		12	90	E4	12	8
	SOT6_0 (SDA6_0)	Multifunction serial interface ch.6 output pin. This pin operates as SOT6 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA6 when it is used in an I ² C (operation mode 4).	6	84	D2	6	-
	SOT6_1 (SDA6_1)		11	89	E3	11	7
	SCK6_0 (SCL6_0)	Multifunction serial interface ch.6 clock I/O pin. This pin operates as SCK6 when it is used in a CSIO (operation mode 2) and as SCL6 when it is used in an I ² C (operation mode 4).	7	85	D3	7	-
	SCK6_1 (SCL6_1)		10	88	E2	10	6
Multi Function Serial 7	SIN7_1	Multifunction serial interface ch.7 input pin	45	23	K8	35	27
	SOT7_1 (SDA7_1)	Multifunction serial interface ch.7 output pin. This pin operates as SOT7 when it is used in a UART/CSIO/LIN (operation modes 0 to 3) and as SDA7 when it is used in an I ² C (operation mode 4).	44	22	J7	34	26
	SCK7_1 (SCL7_1)	Multifunction serial interface ch.7 clock I/O pin. This pin operates as SCK7 when it is used in a CSIO (operation mode 2) and as SCL7 when it is used in an I ² C (operation mode 4).	43	21	H6	33	25

Module	Pin name	Function	Pin No				
			LQFP-100	QFP-100	BGA-112	LQFP-80	LQFP-64 QFN-64
Reset	INITX	External Reset Input. A reset is valid when INITX="L"	38	16	K4	28	21
Mode	MD0	Mode 0 pin. During normal operation, MD0="L" must be input. During serial programming to flash memory, MD0="H" must be input.	47	25	L8	37	29
	MD1	Mode 1 pin. During serial programming to flash memory, MD1="L" must be input.	46	24	K9	36	28
Power	VCC	Power supply pin	1	79	B1	1	1
	VCC	Power supply pin	26	4	J1	-	-
	VCC	Power supply pin	35	13	K1	25	18
	VCC	Power supply pin	51	29	K11	41	33
	VCC	Power supply pin	76	54	A10	-	-
	VCC	Power supply pin	97	75	A4	77	61
GND	VSS	GND pin	-	-	B2	-	-
	VSS	GND pin	25	3	L1	20	16
	VSS	GND pin	-	-	K2	-	-
	VSS	GND pin	-	-	J3	-	-
	VSS	GND pin	-	-	H4	-	-
	VSS	GND pin	34	12	L4	24	-
	VSS	GND pin	50	28	L11	40	32
	VSS	GND pin	-	-	K10	-	-
	VSS	GND pin	-	-	J9	-	-
	VSS	GND pin	-	-	H8	-	-
	VSS	GND pin	-	-	B10	-	-
	VSS	GND pin	-	-	C9	-	-
	VSS	GND pin	75	53	A11	-	-
	VSS	GND pin	-	-	D8	-	-
	VSS	GND pin	-	-	D4	-	-
	VSS	GND pin	-	-	C3	-	-
	VSS	GND pin	100	78	A1	80	64
Clock	X0	Main clock (oscillation) input pin	48	26	L9	38	30
	X0A	Sub clock (oscillation) input pin	36	14	L3	26	19
	X1	Main clock (oscillation) I/O pin	49	27	L10	39	31
	X1A	Sub clock (oscillation) I/O pin	37	15	K3	27	20
	CROUT_0	Built-in high-speed CR-osc clock output port	74	52	C10	60	-
	CROUT_1		92	70	B5	72	57
Analog Power	AVCC	A/D converter analog power supply pin	60	38	H11	50	41
	AVRH	A/D converter analog reference voltage input pin	61	39	F11	51	42
Analog GND	AVSS	A/D converter GND pin	62	40	G11	52	43
C pin	C	Power supply stabilization capacity pin	33	11	L2	23	17

Note:

- While this device contains a Test Access Port (TAP) based on the IEEE 1149.1-2001 JTAG standard, it is not fully compliant to all requirements of that standard. This device may contain a 32-bit device ID that is the same as the 32-bit device ID in other devices with different functionality. The TAP pins may also be configurable for purposes other than access to the TAP controller.

6. Handling Precautions

Any semiconductor devices have inherently a certain rate of failure. The possibility of failure is greatly affected by the conditions in which they are used (circuit conditions, environmental conditions, etc.). This page describes precautions that must be observed to minimize the chance of failure and to obtain higher reliability from your Cypress semiconductor devices.

6.1 Precautions for Product Design

This section describes precautions when designing electronic equipment using semiconductor devices.

Absolute Maximum Ratings

Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of certain established limits, called absolute maximum ratings. Do not exceed these ratings.

Recommended Operating Conditions

Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the datasheet. Users considering application outside the listed conditions are advised to contact their sales representative beforehand.

Processing and Protection of Pins

These precautions must be followed when handling the pins which connect semiconductor devices to power supply and input/output functions.

1. Preventing Over-Voltage and Over-Current Conditions

Exposure to voltage or current levels in excess of maximum ratings at any pin is likely to cause deterioration within the device, and in extreme cases leads to permanent damage of the device. Try to prevent such overvoltage or over-current conditions at the design stage.

2. Protection of Output Pins

Shorting of output pins to supply pins or other output pins, or connection to large capacitance can cause large current flows. Such conditions if present for extended periods of time can damage the device. Therefore, avoid this type of connection.

3. Handling of Unused Input Pins

Unconnected input pins with very high impedance levels can adversely affect stability of operation. Such pins should be connected through an appropriate resistance to a power supply pin or ground pin.

Latch-up

Semiconductor devices are constructed by the formation of P-type and N-type areas on a substrate. When subjected to abnormally high voltages, internal parasitic PNP junctions (called thyristor structures) may be formed, causing large current levels in excess of several hundred mA to flow continuously at the power supply pin. This condition is called latch-up.

CAUTION: The occurrence of latch-up not only causes loss of reliability in the semiconductor device, but can cause injury or damage from high heat, smoke or flame. To prevent this from happening, do the following:

1. Be sure that voltages applied to pins do not exceed the absolute maximum ratings. This should include attention to abnormal noise, surge levels, etc.
2. Be sure that abnormal current flows do not occur during the power-on sequence.

Observance of Safety Regulations and Standards

Most countries in the world have established standards and regulations regarding safety, protection from electromagnetic interference, etc. Customers are requested to observe applicable regulations and standards in the design of products.

Fail-Safe Design

Any semiconductor devices have inherently a certain rate of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

List of Pin Status

Pin status type	Function group	Power-on reset or low-voltage detection state	INITX input state	Device internal reset state	Run mode or SLEEP mode state	Timer mode or STOP mode state	
		Power supply unstable	Power supply stable		Power supply stable	Power supply stable	
		-	INITX=0	INITX=1	INITX=1	INITX=1	
		-	-	-	-	SPL=0	SPL=1
A	GPIO selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Hi-Z/ Internal input fixed at "0"
	Main crystal oscillator input pin	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled
B	GPIO selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Hi-Z/ Internal input fixed at "0"
	Main crystal oscillator output pin	Hi-Z/ Internal input fixed at "0"/ or Input enable	Hi-Z/ Internal input fixed at "0"	Hi-Z/ Internal input fixed at "0"	Maintain previous state	Maintain previous state/ Hi-Z at oscillation stop*1/ Internal input fixed at "0"	Maintain previous state/ Hi-Z at oscillation stop*1/ Internal input fixed at "0"
C	INITX input pin	Pull-up/ Input enabled	Pull-up/ Input enabled	Pull-up/ Input enabled	Pull-up/ Input enabled	Pull-up/ Input enabled	Pull-up/ Input enabled
D	Mode input pin	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled	Input enabled
E	JTAG selected	Hi-Z	Pull-up/ Input enabled	Pull-up/ Input enabled	Maintain previous state	Maintain previous state	Maintain previous state
	GPIO selected	Setting disabled	Setting disabled	Setting disabled			Hi-Z/ Internal input fixed at "0"
F	Trace selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Trace output
	External interrupt enabled selected						Maintain previous state
	GPIO selected, or resource other than above selected	Hi-Z	Hi-Z/ Input enabled	Hi-Z/ Input enabled			Hi-Z/ Internal input fixed at "0"

Pin status type	Function group	Power-on reset or low-voltage detection state	INITX input state	Device internal reset state	Run mode or SLEEP mode state	Timer mode or STOP mode state	
		Power supply unstable	Power supply stable		Power supply stable	Power supply stable	
		-	INITX=0	INITX=1	INITX=1	INITX=1	
		-	-	-	-	SPL=0	SPL=1
G	Trace selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Trace output
	GPIO selected, or resource other than above selected	Hi-Z	Hi-Z/ Input enabled	Hi-Z/ Input enabled			Hi-Z/ Internal input fixed at "0"
H	External interrupt enabled selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state
	GPIO selected, or resource other than above selected	Hi-Z	Hi-Z/ Input enabled	Hi-Z/ Input enabled			Hi-Z/ Internal input fixed at "0"
I	GPIO selected, resource selected	Hi-Z	Hi-Z/ Input enabled	Hi-Z/ Input enabled	Maintain previous state	Maintain previous state	Hi-Z/ Internal input fixed at "0"
J	NMIX selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state
	GPIO selected, or resource other than above selected	Hi-Z	Hi-Z/ Input enabled	Hi-Z/ Input enabled			Hi-Z/ Internal input fixed at "0"
K	Analog input selected	Hi-Z	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled
	GPIO selected, or resource other than above selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Hi-Z/ Internal input fixed at "0"
L	External interrupt enabled selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Maintain previous state
	Analog input selected	Hi-Z	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled	Hi-Z/ Internal input fixed at "0"/ Analog input enabled
	GPIO selected, or resource other than above selected	Setting disabled	Setting disabled	Setting disabled	Maintain previous state	Maintain previous state	Hi-Z/ Internal input fixed at "0"

12. Electrical Characteristics

12.1 Absolute Maximum Ratings

Parameter	Symbol	Rating		Unit	Remarks
		Min	Max		
Power supply voltage* ¹ , * ²	V_{CC}	$V_{SS} - 0.5$	$V_{SS} + 6.5$	V	
Analog power supply voltage* ¹ , * ³	AV_{CC}	$V_{SS} - 0.5$	$V_{SS} + 6.5$	V	
Analog reference voltage* ¹ , * ³	AV_{RH}	$V_{SS} - 0.5$	$V_{SS} + 6.5$	V	
Input voltage* ¹	V_I	$V_{SS} - 0.5$	$V_{CC} + 0.5$ ($\leq 6.5V$)	V	
		$V_{SS} - 0.5$	$V_{SS} + 6.5$	V	5V tolerant
Analog pin input voltage* ¹	V_{IA}	$V_{SS} - 0.5$	$AV_{CC} + 0.5$ ($\leq 6.5V$)	V	
Output voltage* ¹	V_O	$V_{SS} - 0.5$	$V_{CC} + 0.5$ ($\leq 6.5V$)	V	
Clamp maximum current	I_{CLAMP}	-2	+2	mA	* ⁷
Clamp total maximum current	$\sum I_{CLAMP}$		+20	mA	* ⁷
"L" level maximum output current* ⁴	I_{OL}	-	10	mA	4mA type
			20	mA	12mA type
			39	mA	P80, P81
"L" level average output current* ⁵	I_{OLAV}	-	4	mA	4mA type
			12	mA	12mA type
			18.5	mA	P80, P81
"L" level total maximum output current	$\sum I_{OL}$	-	100	mA	
"L" level total average output current* ⁶	$\sum I_{OLAV}$	-	50	mA	
"H" level maximum output current* ⁴	I_{OH}	-	- 10	mA	4mA type
			- 20	mA	12mA type
			- 39	mA	P80, P81
"H" level average output current* ⁵	I_{OHAV}	-	- 4	mA	4mA type
			- 12	mA	12mA type
			- 20.5	mA	P80, P81
"H" level total maximum output current	$\sum I_{OH}$	-	- 100	mA	
"H" level total average output current* ⁶	$\sum I_{OHAV}$	-	- 50	mA	
Power consumption	P_D	-	300	mW	
Storage temperature	T_{STG}	- 55	+ 150	°C	

*1: These parameters are based on the condition that $V_{SS} = AV_{SS} = 0.0V$.

*2: V_{CC} must not drop below $V_{SS} - 0.5V$.

*3: Be careful not to exceed $V_{CC} + 0.5 V$, for example, when the power is turned on.

*4: The maximum output current is defined as the value of the peak current flowing through any one of the corresponding pins.

*5: The average output current is defined as the average current value flowing through any one of the corresponding pins for a 100ms period.

*6: The total average output current is defined as the average current value flowing through all of corresponding pins for a 100ms.

12.2 Recommended Operating Conditions

(V_{SS} = AV_{SS} = 0.0V)

Parameter		Symbol	Conditions	Value		Unit	Remarks
				Min	Max		
Power supply voltage		V _{CC}	-	2.7 ^{*2}	5.5	V	
Analog power supply voltage		AV _{CC}	-	2.7	5.5	V	AV _{CC} = V _{CC}
Analog reference voltage		AVRH	-	2.7	AV _{CC}	V	
Smoothing capacitor		C _S	-	1	10	μF	For built-in regulator ^{*1}
Operating temperature	LQI100 LQH080 LQD064 LQG064 VNC064 LBC112	T _A	-	- 40	+ 105	°C	
	PQH100	T _A	When mounted on four-layer PCB	- 40	+ 105	°C	
			When mounted on double-sided single-layer PCB	- 40	+ 105	°C	I _{CC} ≤ 35mA
				- 40	+ 85	°C	I _{CC} > 35mA

*1: See "C Pin" in "7. Handling Devices" for the connection of the smoothing capacitor.

*2: In between less than the minimum power supply voltage and low voltage reset/interrupt detection voltage or more, instruction execution and low voltage detection function by built-in High-speed CR(including Main PLL is used) or built-in Low-speed CR is possible to operate only.

WARNING:

The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure. No warranty is made with respect to uses, operating conditions, or combinations not represented on the datasheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

12.3 DC Characteristics

12.3.1 Current rating

($V_{CC} = AV_{CC} = 2.7V$ to $5.5V$, $V_{SS} = AV_{SS} = 0V$, $T_A = -40^{\circ}C$ to $+105^{\circ}C$)

Parameter	Symbol	Pin name	Conditions	Value		Unit	Remarks
				Typ ^{*3}	Max ^{*4}		
RUN mode current	I_{CC}	VCC	PLL RUN mode CPU : 40MHz, Peripheral : 40MHz, Flash 0Wait FRWTR.RWT = 00 FSYNDN.SD = 000 ^{*5}	32	41	mA	*1
			PLL RUN mode CPU : 40MHz, Peripheral : 40MHz, Flash 3Wait FRWTR.RWT = 00 FSYNDN.SD = 011 ^{*5}	21	28	mA	*1
			High-speed CR RUN mode CPU/ Peripheral : 4MHz ^{*2} Flash 0Wait FRWTR.RWT = 00 FSYNDN.SD = 000	3.9	7.7	mA	*1
			Sub RUN mode CPU/ Peripheral : 32kHz Flash 0Wait FRWTR.RWT = 00 FSYNDN.SD = 000 ^{*6}	0.15	3.2	mA	*1
			Low-speed CR RUN mode CPU/ Peripheral : 100kHz Flash 0Wait FRWTR.RWT = 00 FSYNDN.SD = 000	0.2	3.3	mA	*1
SLEEP mode current	I_{CCS}	VCC	PLL SLEEP mode Peripheral : 40MHz ^{*5}	10	15	mA	*1
			High-speed CR SLEEP mode Peripheral : 4MHz ^{*2}	1.2	4.4	mA	*1
			Sub SLEEP mode Peripheral : 32kHz ^{*6}	0.1	3.1	mA	*1
			Low-speed CR SLEEP mode Peripheral : 100kHz	0.1	3.1	mA	*1

*1: When all ports are fixed.

*2: When setting it to 4MHz by trimming.

*3: $T_A = +25^{\circ}C$, $V_{CC} = 5.5V$

*4: $T_A = +105^{\circ}C$, $V_{CC} = 5.5V$

*5: When using the crystal oscillator of 4 MHz(Including the current consumption of the oscillation circuit)

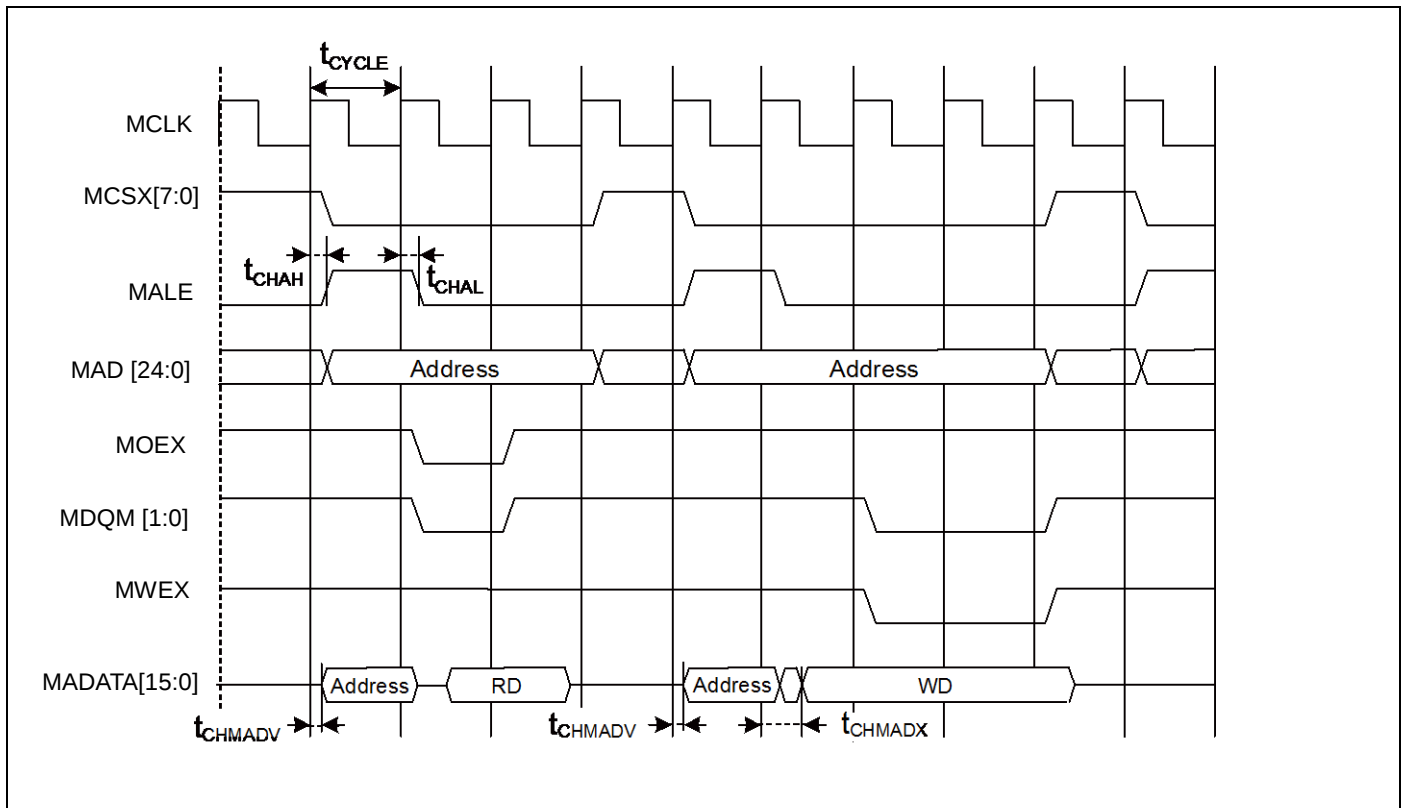
*6: When using the crystal oscillator of 32 kHz(Including the current consumption of the oscillation circuit)

Multiplexed Bus Access Synchronous SRAM Mode

($V_{CC} = 2.7V$ to $5.5V$, $V_{SS} = 0V$, $T_A = -40^{\circ}C$ to $+105^{\circ}C$)

Parameter	Symbol	Pin name	Conditions	Value		Unit	Remarks
				Min	Max		
MALE delay time	t _{CHAL}	MCLK ALE	V _{CC} ≥ 4.5V	1	9	ns	
	V _{CC} < 4.5V		12		ns		
	t _{CHAH}		V _{CC} ≥ 4.5V	1	9	ns	
			V _{CC} < 4.5V		12	ns	
MCLK ↑→ Multiplexed Address delay time	t _{CHMADV}	MCLK MADATA[15:0]	V _{CC} ≥ 4.5V	1	t _{OD}	ns	
			V _{CC} < 4.5V				
MCLK ↑→ Multiplexed Data output time	t _{CHMADX}		V _{CC} ≥ 4.5V	1	t _{OD}	ns	
			V _{CC} < 4.5V				

Note: When the external load capacitance $C_L = 30pF$.



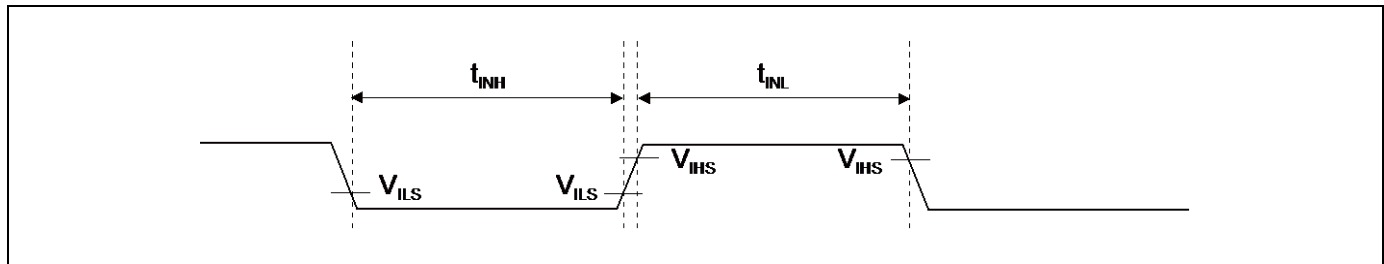
12.4.11 External Input Timing

($V_{CC} = 2.7V$ to $5.5V$, $V_{SS} = 0V$, $T_A = -40^{\circ}C$ to $+105^{\circ}C$)

Parameter	Symbol	Pin name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{INH} t_{INL}	ADTG	-	$2t_{CYCP}^*$	-	ns	A/D converter trigger input
		FRCKx					Free-run timer input clock
		ICxx					Input capture
		DTTlxX	-	$2t_{CYCP}^*$	-	ns	Wave form generator
		INTxx, NMIX	Except Timer mode, Stop mode	$2t_{CYCP} + 100^*$	-	ns	External interrupt NMI
			Timer mode, Stop mode	500	-	ns	

*1: t_{CYCP} indicates the APB bus clock cycle time.

About the APB bus number which the A/D converter, Multi-function Timer, External interrupt are connected to, see "8. Block Diagram" in this datasheet.



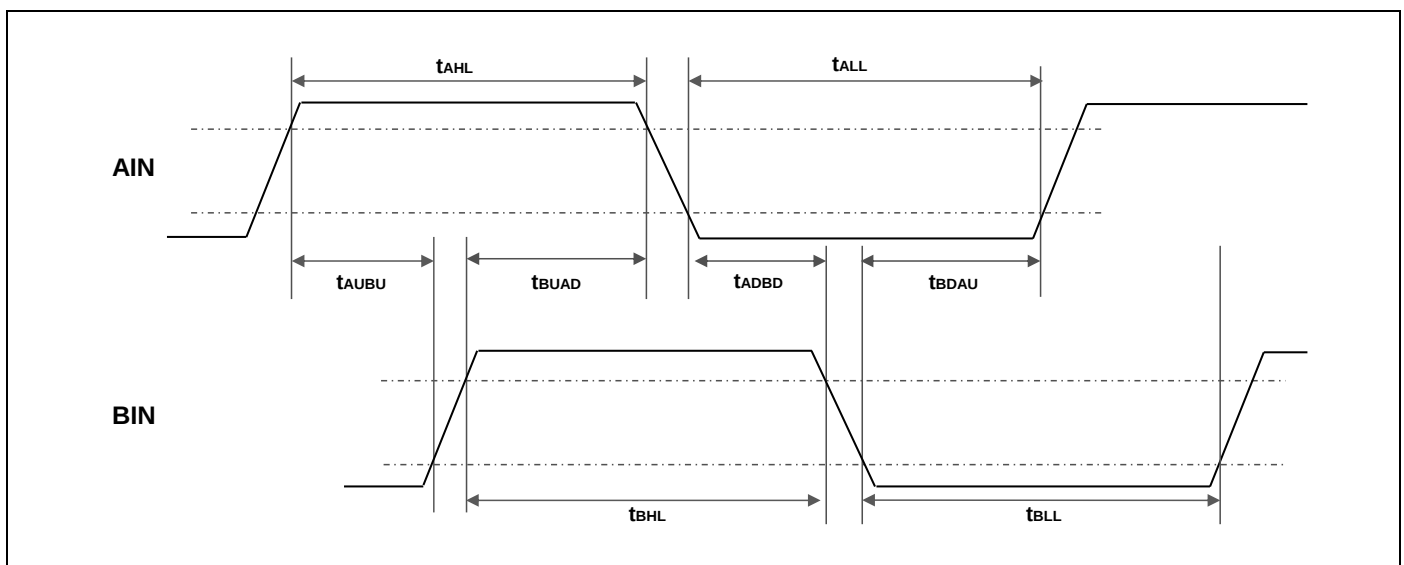
12.4.12 Quadrature Position/Revolution Counter timing

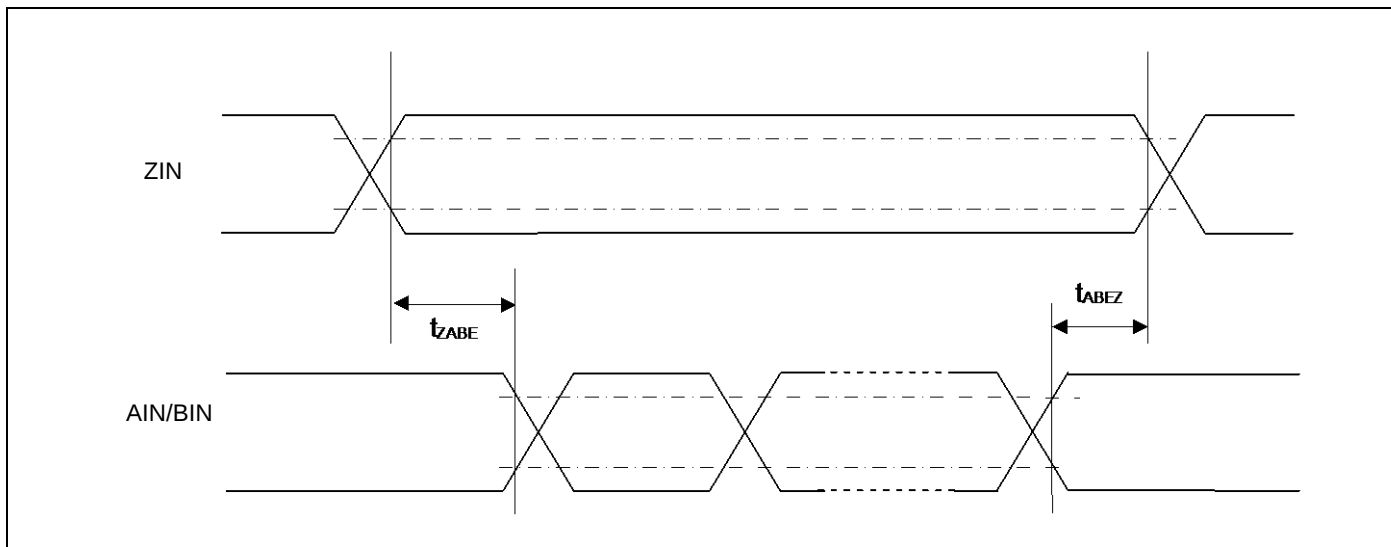
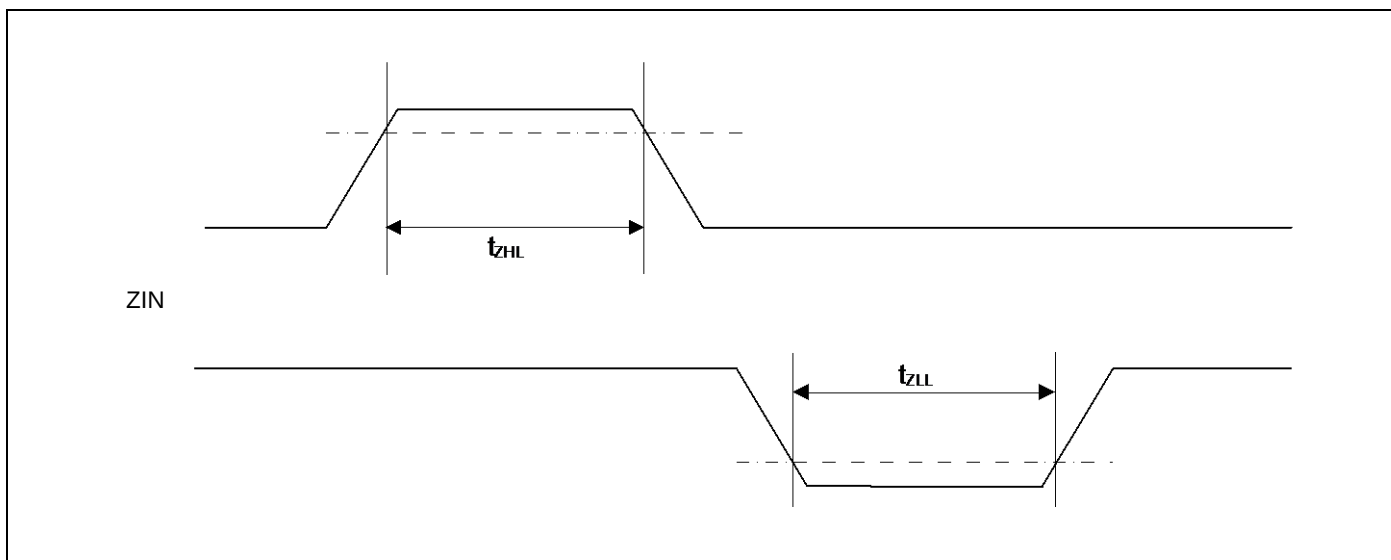
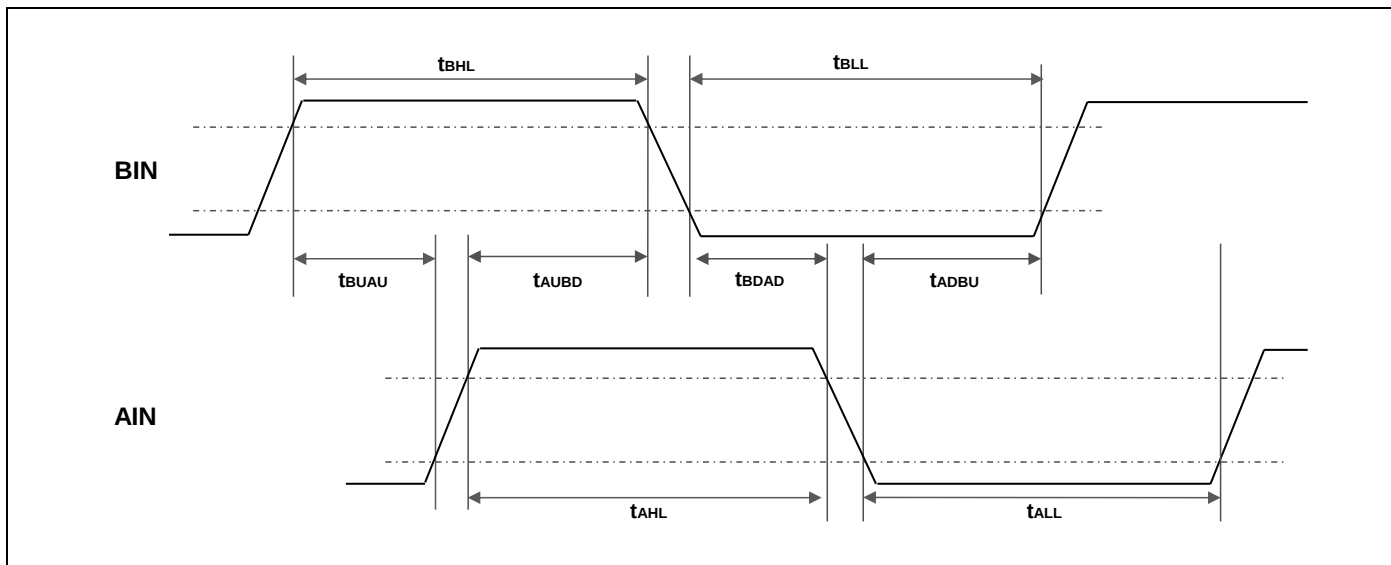
($V_{CC} = 2.7V$ to $5.5V$, $V_{SS} = 0V$, $T_A = -40^{\circ}C$ to $+105^{\circ}C$)

Parameter	Symbol	Conditions	Value		Unit
			Min	Max	
AIN pin "H" width	t_{AHL}	-	$2t_{CYCP}^*$	-	ns
AIN pin "L" width	t_{ALL}	-			
BIN pin "H" width	t_{BHL}	-			
BIN pin "L" width	t_{BLL}	-			
BIN rise time from AIN pin "H" level	t_{AUBU}	PC_Mode2 or PC_Mode3			
AIN fall time from BIN pin "H" level	t_{BUAD}	PC_Mode2 or PC_Mode3			
BIN fall time from AIN pin "L" level	t_{ADBD}	PC_Mode2 or PC_Mode3			
AIN rise time from BIN pin "L" level	t_{BDAU}	PC_Mode2 or PC_Mode3			
AIN rise time from BIN pin "H" level	t_{BUAU}	PC_Mode2 or PC_Mode3			
BIN fall time from AIN pin "H" level	t_{AUBD}	PC_Mode2 or PC_Mode3			
AIN fall time from BIN pin "L" level	t_{BDAD}	PC_Mode2 or PC_Mode3			
BIN rise time from AIN pin "L" level	t_{ADBU}	PC_Mode2 or PC_Mode3			
ZIN pin "H" width	t_{ZHL}	QCR:CGSC = "0"			
ZIN pin "L" width	t_{ZLL}	QCR:CGSC = "0"			
AIN/BIN rise and fall time from determined ZIN level	t_{ZABE}	QCR:CGSC = "1"			
Determined ZIN level from AIN/BIN rise and fall time	t_{ABEZ}	QCR:CGSC = "1"			

*: t_{CYCP} indicates the APB bus clock cycle time.

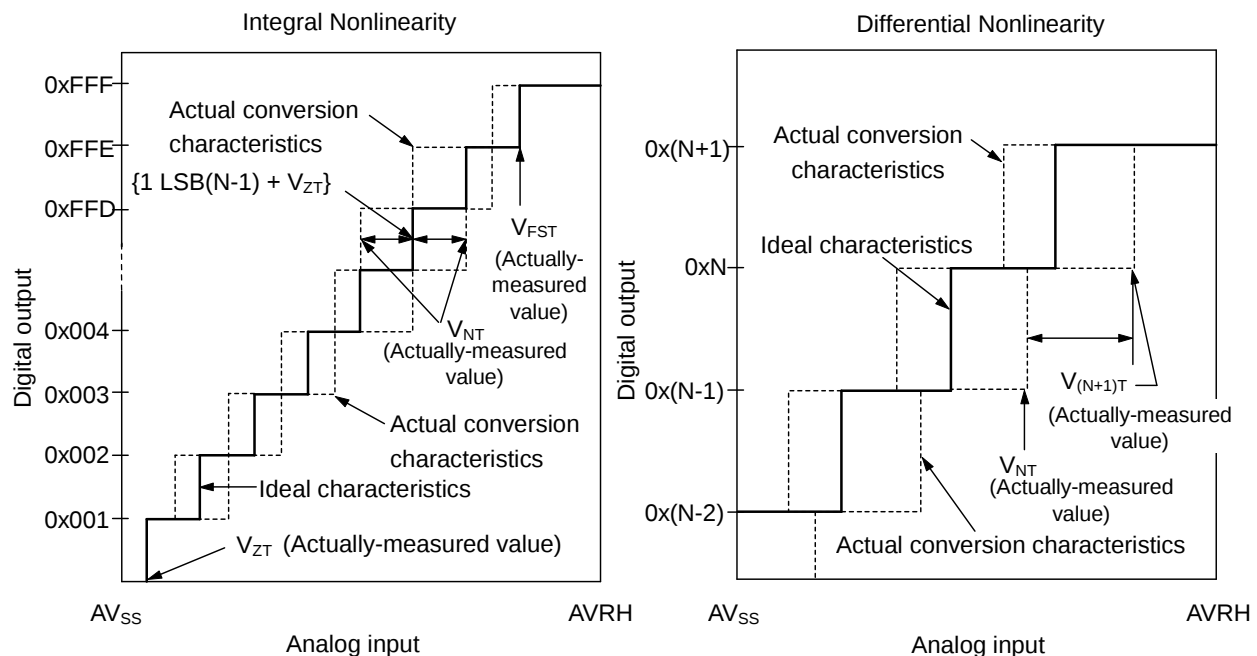
About the APB bus number which Quadrature Position/Revolution Counter is connected to, see "8. Block Diagram" in this datasheet.





Definition of 12-bit A/D Converter Terms

- Resolution : Analog variation that is recognized by an A/D converter.
- Integral Nonlinearity : Deviation of the line between the zero-transition point (0b000000000000 ↔ 0b000000000001) and the full-scale transition point (0b111111111110 ↔ 0b111111111111) from the actual conversion characteristics.
- Differential Nonlinearity : Deviation from the ideal value of the input voltage that is required to change the output code by 1 LSB.



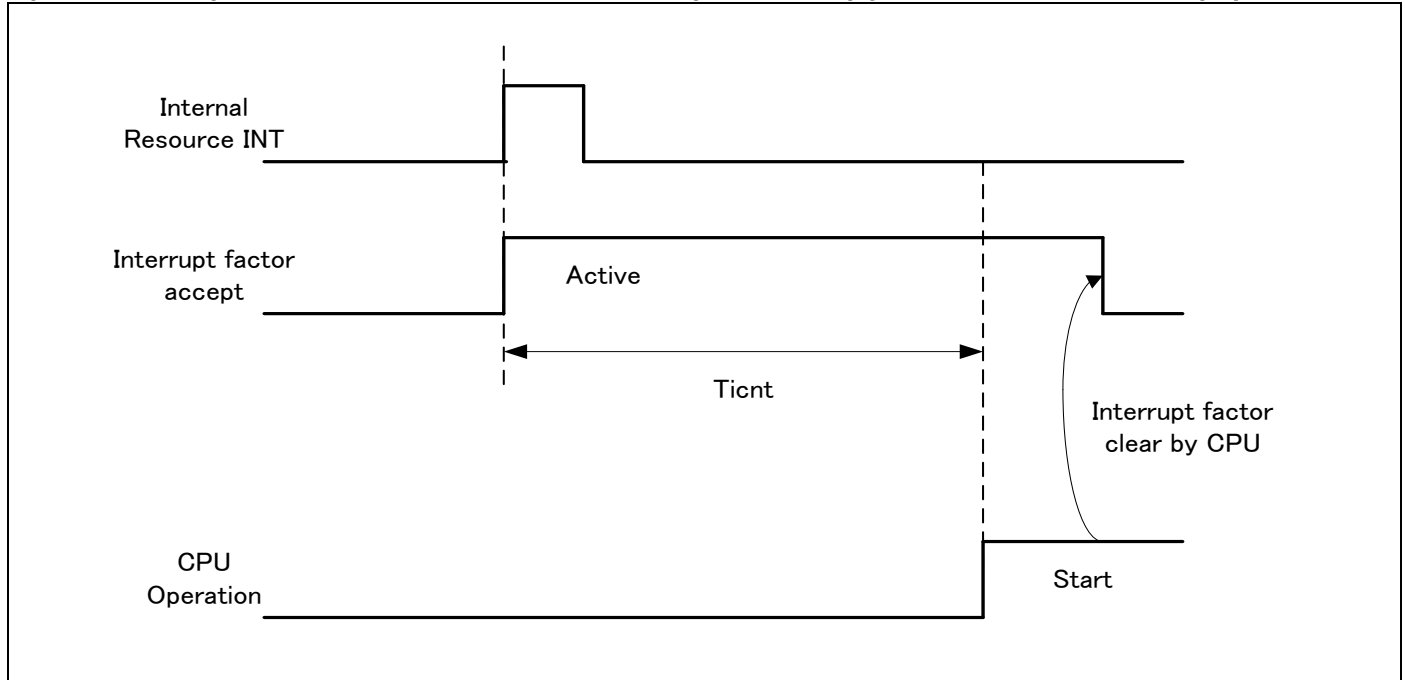
$$\text{Integral Nonlinearity of digital output } N = \frac{V_{NT} - \{1\text{LSB} \times (N - 1) + V_{ZT}\}}{1\text{LSB}} \quad [\text{LSB}]$$

$$\text{Differential Nonlinearity of digital output } N = \frac{V_{(N+1)T} - V_{NT}}{1\text{LSB}} - 1 \quad [\text{LSB}]$$

$$1\text{LSB} = \frac{V_{FST} - V_{ZT}}{4094}$$

- N : A/D converter digital output value.
 V_{ZT} : Voltage at which the digital output changes from 0x000 to 0x001.
 V_{FST} : Voltage at which the digital output changes from 0xFFE to 0xFFF.
 V_{NT} : Voltage at which the digital output changes from 0x(N - 1) to 0xN.

Operation example of return from Low-Power consumption mode (by internal resource interrupt*)



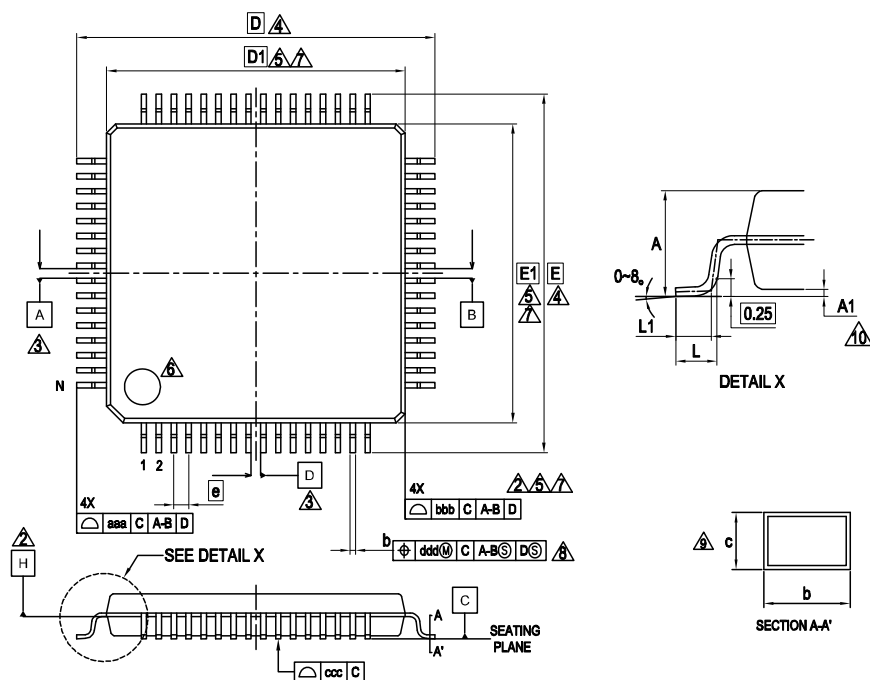
*: Internal resource interrupt is not included in return factor by the kind of Low-Power consumption mode.

Notes:

- The return factor is different in each Low-Power consumption modes.
See "Chapter 6: Low Power Consumption Mode" and "Operations of Standby Modes" in FM3 Family Peripheral Manual about the return factor from Low-Power consumption mode.
- When interrupt recovers, the operation mode that CPU recovers depends on the state before the Low-Power consumption mode transition. See "Chapter 6: Low Power Consumption Mode" in "FM3 Family Peripheral Manual".

Package Type	Package Code
LQFP 64	LQD064

LQD064-02, 64 Lead Plastic Low Profile Quad Flat Package



PACKAGE	LQD64-02		
SYMBOL	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.00	—	0.20
b	0.17	0.22	0.27
c	0.09	—	0.20
D	12.00 BSC.		
D1	10.00 BSC.		
e	0.50 BSC.		
E	12.00 BSC.		
E1	10.00 BSC.		
L	0.45	0.60	0.75
L1	0.30	0.50	0.70
aaa	—	—	0.20
bbb	—	—	0.10
ccc	—	—	0.08
ddd	—	—	0.08
N	64		

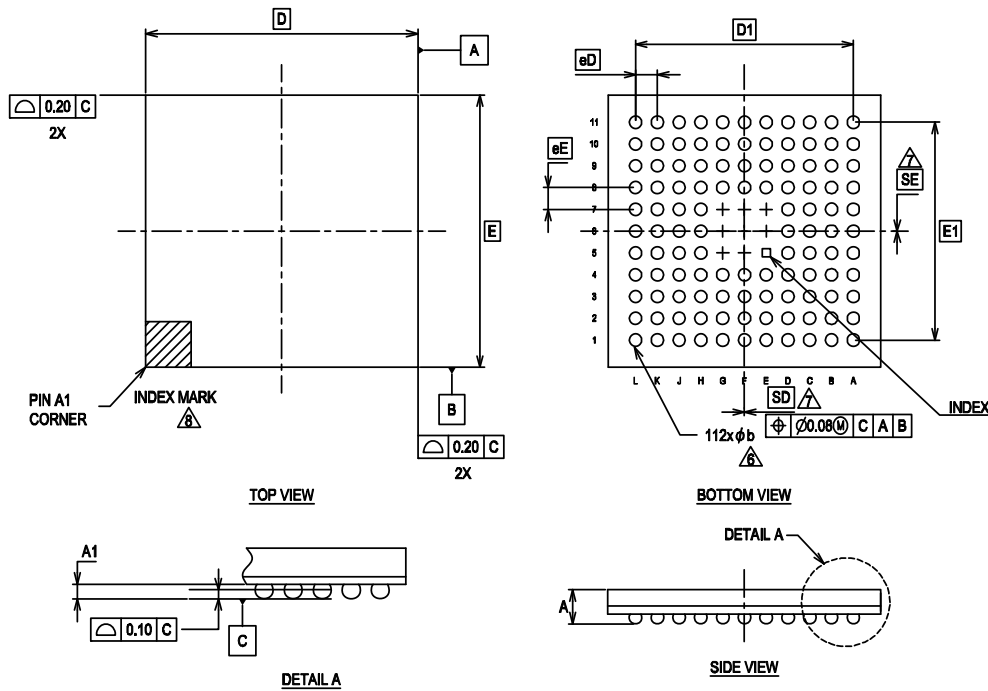
NOTES

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm)
2. DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
3. DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
4. TO BE DETERMINED AT SEATING PLANE C.
5. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
6. DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
7. REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS, DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS. BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
8. DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBER PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
9. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
10. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

Rev. A

Package Type	Package Code
PFBGA 112	LBC112

LBC112 112 BALL LOW PROFILE FINE PITCH BALL GRID ARRAY PACKAGE



PACKAGE	LBC112			NOTE
SYMBOL	MIN.	NOM.	MAX.	
A	—	—	1.45	PROFILE
A1	0.25	0.35	0.45	TERMINAL HEIGHT
D	10.00 BSC			BODY SIZE
E	10.00 BSC			BODY SIZE
D1	8.00 BSC			MATRIX FOOTPRINT
E1	8.00 BSC			MATRIX FOOTPRINT
MD	11			MATRIX SIZE D DIRECTION
ME	11			MATRIX SIZE E DIRECTION
n	112			BALL COUNT
φb	0.35	0.45	0.55	BALL DIAMETER
eD	0.80 BSC			BALL PITCH
eE	0.80 BSC			BALL PITCH
SD/SE	0.00			SOLDER BALL PLACEMENT
	E5,E6,E7,F5,F6,F7,G5,G6 G7			DEPOPULATED SOLDER BALL LOCATIONS

- DIMENSIONS AND TOLERANCES METHODS PER ASME Y14.5-2009. THIS OUTLINE CONFORMS TO JEP95, SECTION 4.5.
- ALL DIMENSIONS ARE IN MILLIMETERS.
- BALL POSITION DESIGNATION PER JEP95, SECTION 3, SPP-010.
- Ⓢ REPRESENTS THE SOLDER BALL GRID PITCH.
- SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION. SYMBOL "ME" IS THE BALL MATRIX SIZE IN THE "E" DIRECTION. n IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
- Ⓢ DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.
- Ⓢ SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW. WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = 0. WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = 1/2.
- Ⓢ A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK. METALLIZED MARK INDENTATION OR OTHER MEANS.
- Ⓢ "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.

Rev. 0A